

L Number	Hits	Search Text	DB	Time stamp
1	2734067	memory or storage	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/02 17:15
2	42522	(memory or storage) and writ\$5 with cell	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/02 17:15
3	2362	((memory or storage) and writ\$5 with cell) and gate with (ground or vss) with cell	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/02 17:18
4	2043	((((memory or storage) and writ\$5 with cell) and gate with (ground or vss) with cell) and (control adj gate or word or wordline) with (potential or voltage or level)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/02 17:18
5	1894	(((((memory or storage) and writ\$5 with cell) and gate with (ground or vss) with cell) and (control adj gate or word or wordline) with (potential or voltage or level)) and gate with (voltage or potential or level) with cell	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/02 17:19
6	271	((((((memory or storage) and writ\$5 with cell) and gate with (ground or vss) with cell) and (control adj gate or word or wordline) with (potential or voltage or level)) and gate with (voltage or potential or level) with cell) and read\$5 with writ\$5 with enabl\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/02 17:19
7	4	((((((((memory or storage) and writ\$5 with cell) and gate with (ground or vss) with cell) and (control adj gate or word or wordline) with (potential or voltage or level)) and gate with (voltage or potential or level) with cell) and read\$5 with writ\$5 with enabl\$5) and source with electrically near float\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/02 17:20